

### APT100DL60B(G) APT100DL60S(G) 600V 100A

\*G Denotes RoHS Compliant, Pb Free Terminal Finish.

# Ultrasoft Recovery Rectifier Diode

#### PRODUCT APPLICATIONS

- Anti-Parallel Diode
   -Switchmode Power Supply
   -Inverters
- Applications

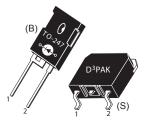
   Induction Heating
- Resonant Mode Circuits
   -ZVS and ZCS Topologies
   Phase Shifted Bridge

#### PRODUCT FEATURES

- Ultrasoft Recovery Times (trr)
- Popular TO-247 Package or Surface Mount D<sup>3</sup>PAK Package
- Ultra Low Forward Voltage
- Low Leakage Current

#### PRODUCT BENEFITS

- Soft Switching High Q<sub>rr</sub>
   Low Noise Switching
- Reduced Ringing
- Higher Reliability Systems
- Minimizes or eliminates
   snubber





<sup>1 -</sup> Cathode 2 - Anode Back of Case - Cathode

#### **MAXIMUM RATINGS**

## All Ratings: $T_{C} = 25^{\circ}C$ unless otherwise specified.

Symbol	Characteristic / Test Conditions	Ratings	Unit
V <sub>R</sub>	Maximum D.C. Reverse Voltage		
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage	600	Volts
V <sub>RWM</sub>	Maximum Working Peak Reverse Voltage		
I <sub>F(AV)</sub>	Maximum Average Forward current $^{(1)}$ (T <sub>c</sub> = 124°C, Duty Cycle = 0.5)	100	
I <sub>F(RMS)</sub>	RMS Forward Currrent (Square wave, 50% duty)	131	Amps
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current (T <sub>j</sub> = 45°C, 8.3 ms)	600	
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to 175	J°
TL	Lead Temperature for 10 Seconds	300	L L

#### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions		Min	Тур	Max	Unit
V <sub>F</sub>		I <sub>F</sub> = 100A		1.25	1.6	Volts
		I <sub>F</sub> = 200A		2.0		
		I <sub>F</sub> = 100A, T <sub>J</sub> = 125°C		1.28		
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> = 600V			25	- μΑ
		V <sub>R</sub> = 600V, T <sub>J</sub> = 125°C			250	
C <sub>T</sub>	Junction Capacitance, V <sub>R</sub> = 200V			97		pF

#### **DYNAMIC CHARACTERISTICS**

#### APT100DL60B\_S(G)

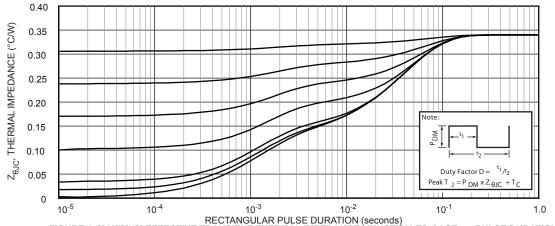
Symbol	Characteristic / Test Conditions		Min	Тур	Max	Unit
t <sub>rr</sub>	Reverse Recovery Time $I_F = 1A$ , $di_F/dt = -100A/\mu s$ , $V_R = 30V$ , $T_J = 25^{\circ}C$			45		
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 100A, di <sub>F</sub> /dt = -200A/ μs V <sub>R</sub> = 400V, T <sub>C</sub> = 25°C		487		ns
Q <sub>rr</sub>	Reverse Recovery Charge			2328		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current			11		Amps
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 100A, di <sub>F</sub> /dt = -200A/μs V <sub>R</sub> = 400V, T <sub>C</sub> = 125°C		716		ns
Q <sub>rr</sub>	Reverse Recovery Charge			5954		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current			18		Amps
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 100A, di <sub>F</sub> /dt = -1000A/ μs V <sub>R</sub> = 400V, T <sub>C</sub> = 125°C		333		ns
Q <sub>rr</sub>	Reverse Recovery Charge			10002		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current			49		Amps

#### THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	Min	Тур	Max	Unit
R <sub>ejc</sub>	Junction-to-Case Thermal Resistance			0.34	°C/W
W <sub>T</sub>	Package Weight		0.22		oz
			5.9		g
Torque	Maximum Mounting Torque			10	lb∙in
				1.1	N∙m

① Continuous current limited by package lead temperature.

Microsemi reserves the right to change, without notice, the specifications and information contained herein.



RECTANGULAR PULSE DURATION (seconds) FIGURE 1. MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs. PULSE DURATION

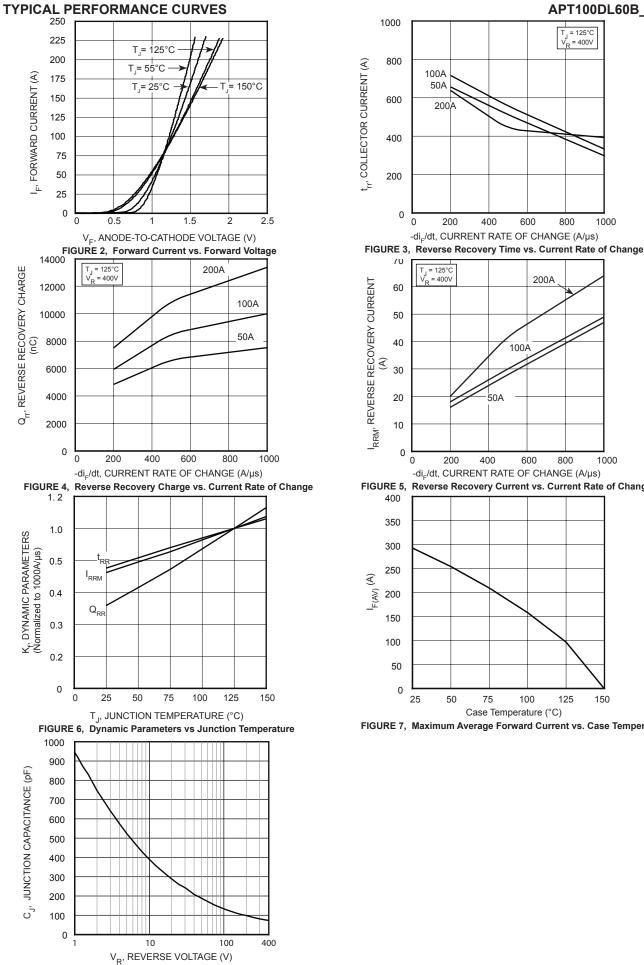


FIGURE 8, Junction Capacitance vs. Reverse Voltage

200A 100A

600

800

1000

600

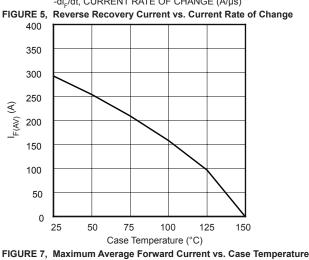
800

1000

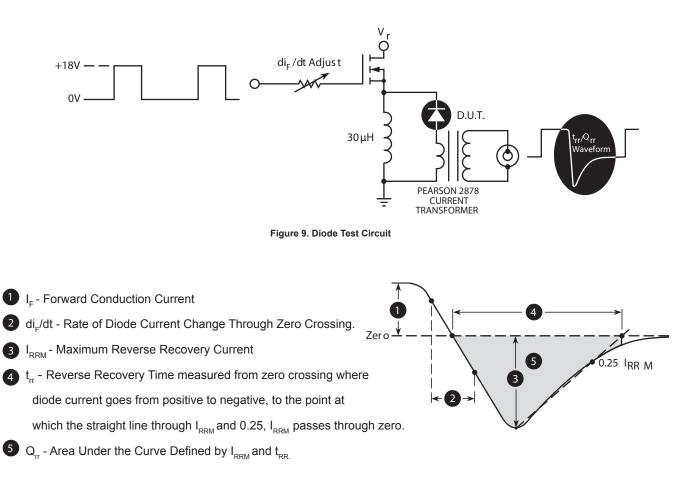
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= 125°C

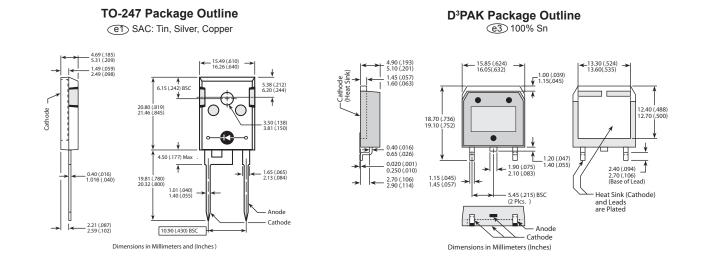
= 400V











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